

Supporting Information for

Built-In Electric Field-Driven Ultrahigh-Rate K-Ion Storage via Heterostructure Engineering of Dual Tellurides Integrated with $\text{Ti}_3\text{C}_2\text{T}_x$ MXene

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Supplementary Figures and Tables

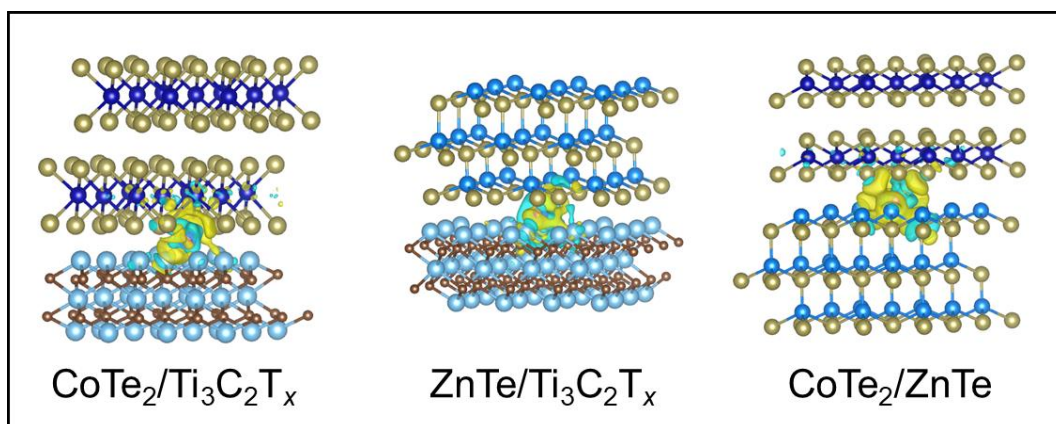


Fig. S1 Charge differences of K^+ adsorption in CoTe_2 , ZnTe , and $\text{CoTe}_2/\text{ZnTe}$

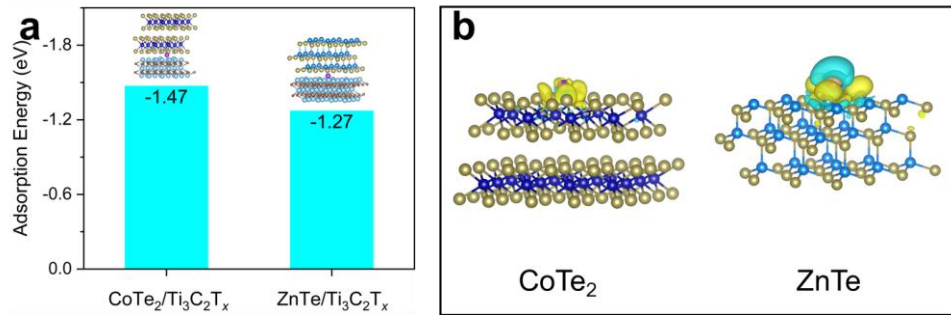


Fig. S2 (a) K^+ adsorption energy and (b) K^+ adsorption charge differences of $CoTe_2/Ti_3C_2T_x$ (CT) and $ZnTe/Ti_3C_2T_x$ (ZT)

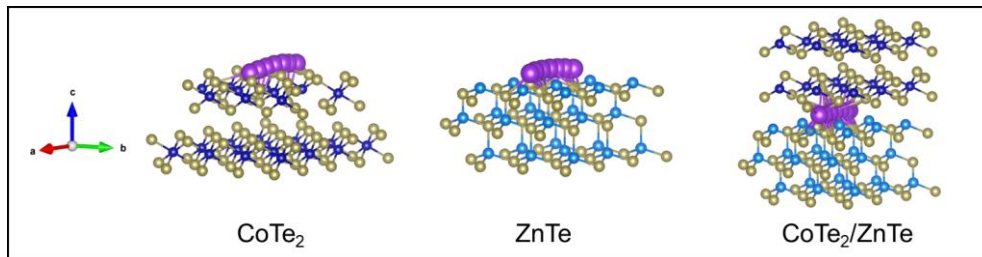


Fig. S3 Side views of the K^+ diffusion routes in $CoTe_2$, $ZnTe$ and $CoTe_2/ZnTe$

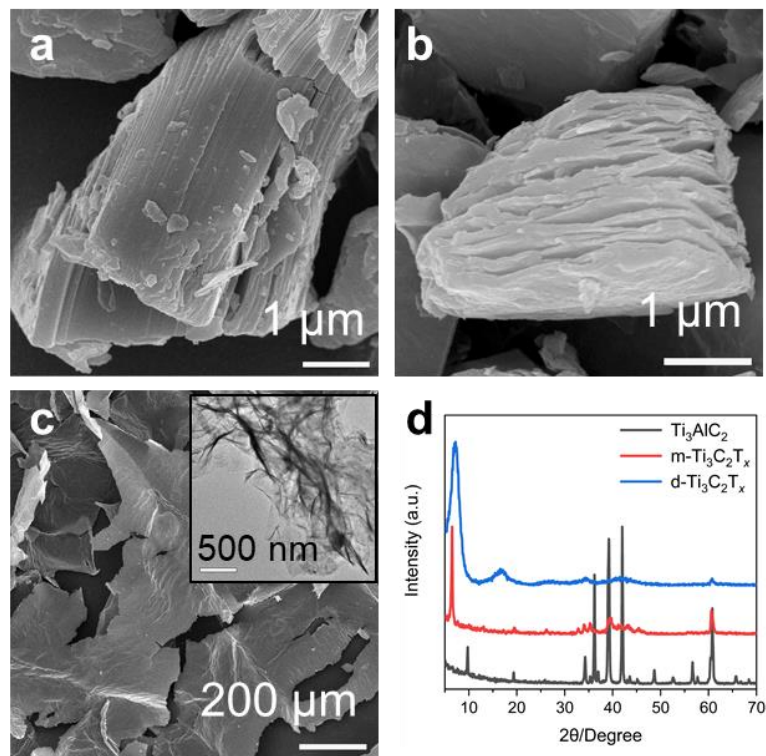


Fig. S4 SEM images of (a) Ti_3AlC_2 MAX phase, (b) multi-layered $Ti_3C_2T_x$, and (c) exfoliated $Ti_3C_2T_x$ nanosheets. (d) XRD patterns of Ti_3AlC_2 MAX phase, multi-layered $Ti_3C_2T_x$, and exfoliated $Ti_3C_2T_x$ nanosheets. The inset of (c) shows TEM image of exfoliated $Ti_3C_2T_x$ nanosheets

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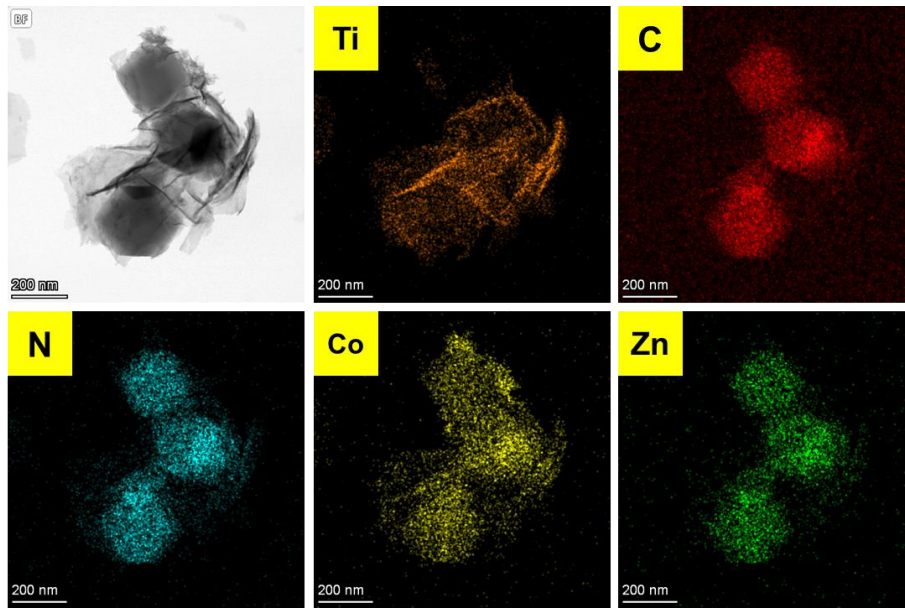


Fig. S5 Elemental mappings of CoZn-MOF/Ti₃C₂T_x

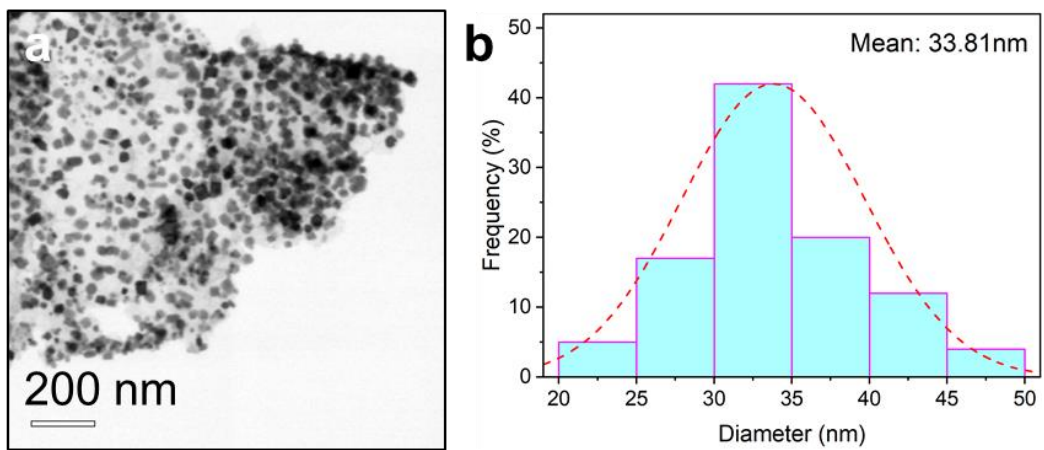


Fig. S6 Size distribution of CoTe₂/ZnTe particles. 100 particles were counted

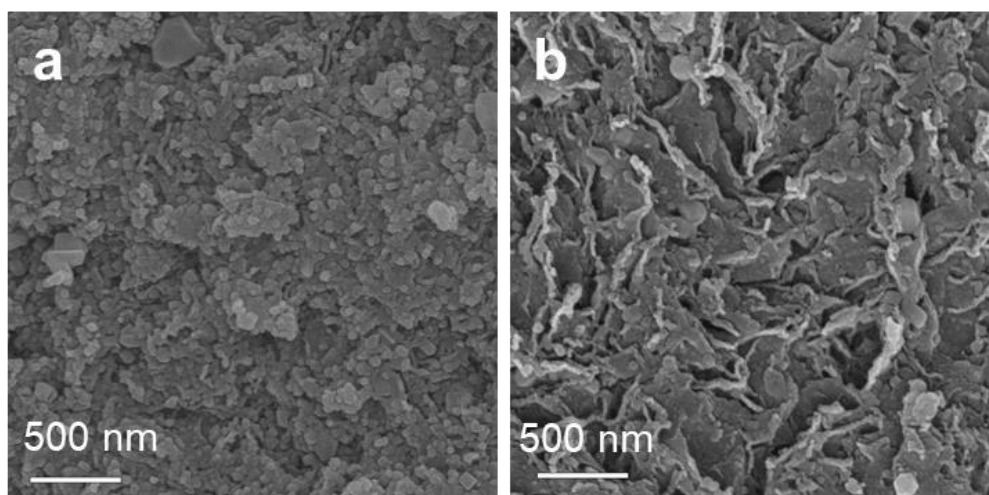


Fig. S7 SEM images of (a) CT and (b) ZT

Table S1 Atomic ratios of Co and Zn in CoZn-MOF/Ti₃C₂T_x and CZT

Sample	Co (at%)	Zn (at%)	Co/Zn Atomic Ratio
CoZn-MOF/Ti ₃ C ₂ T _x	13.9	10.0	1.39
CZT	8.89	6.09	1.45

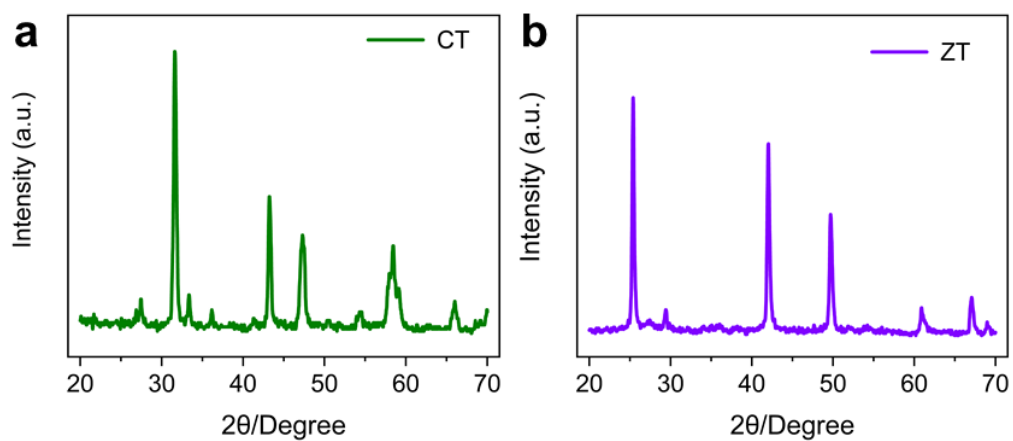


Fig. S8 XRD patterns of (a) CT and (b) ZT

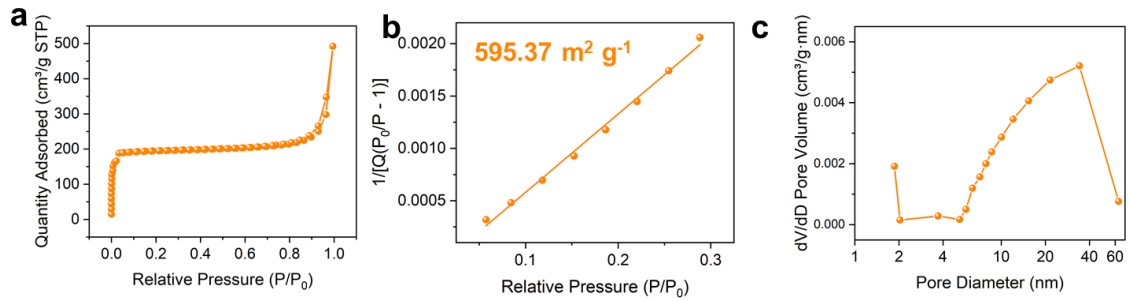


Fig. S9 (a) Nitrogen adsorption-desorption isotherms, (b) BET surface area, and (c) pore size distribution of CoZn-MOF/Ti₃C₂T_x. The CoZn-MOF/Ti₃C₂T_x exhibits a pore volume of 0.76 cm³ g⁻¹ with an average pore size of 34.2 nm

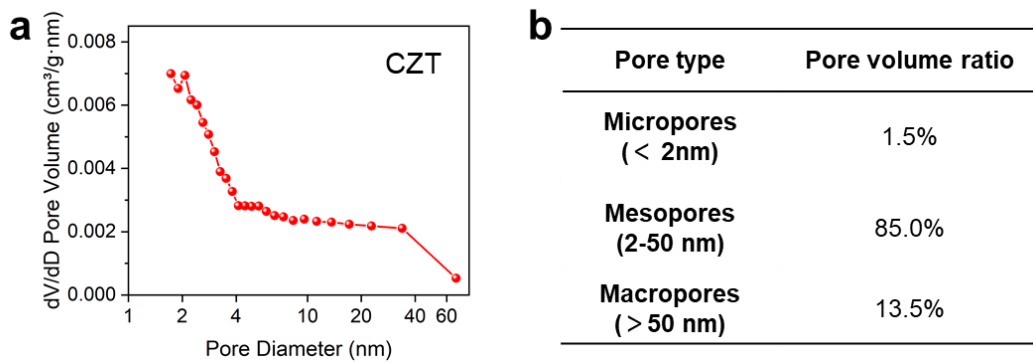


Fig. S10 (a) Pore size distribution and (b) pore volume ratios of CZT

Table S2 Comparison of binding energy in CT, ZT, and CZT

XPS peak		CT (eV)	ZT (eV)	CZT (eV)
Co 2p	Satellite	802.32	-	801.95
	2p _{1/2}	796.40	-	795.90
	Satellite	785.57	-	785.23
	2p _{3/2}	780.45	-	780.18
Zn 2p	2p _{1/2}	-	1044.60	1044.39
	2p _{3/2}	-	1021.49	1021.28
Te 3d	Oxide	586.24	586.32	586.05
	3d _{3/2}	582.97	583.45	582.94
	Oxide	575.84	575.95	575.68
	3d _{5/2}	572.58	572.58	572.57

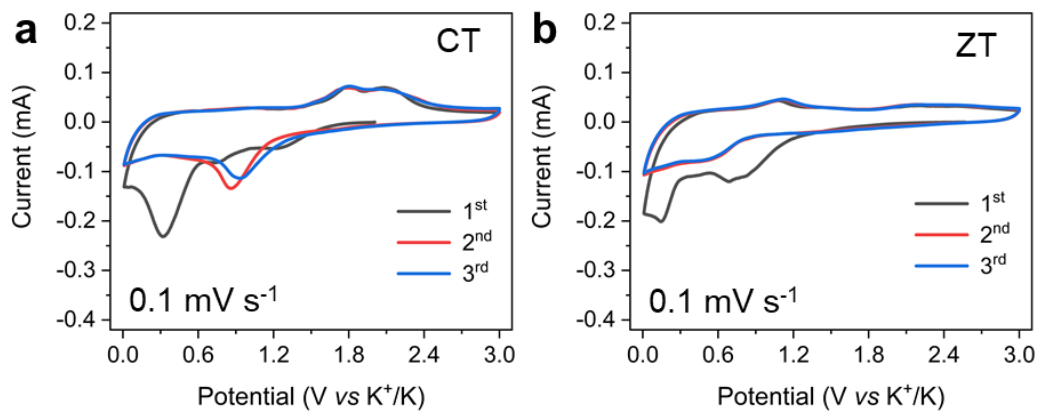


Fig. S11 The first three CV curves of CT and ZT at a scanning rate of 0.1 mV s^{-1}

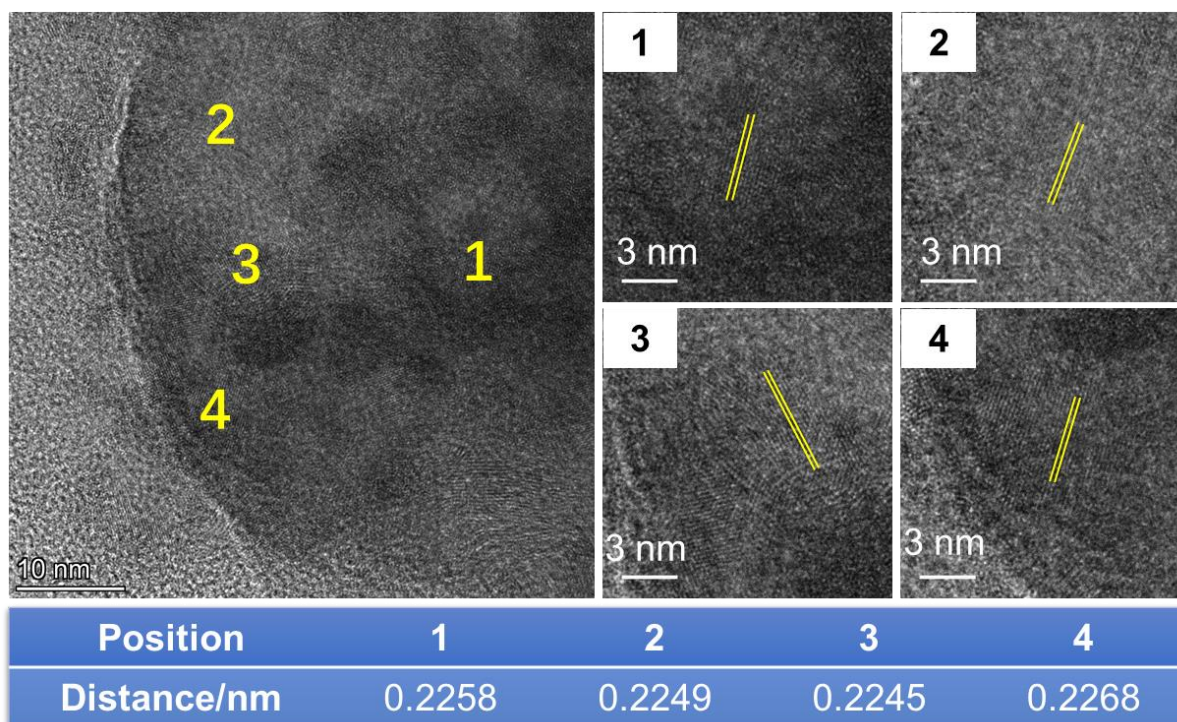


Fig. S12 TEM images of CZT discharged to 0.01 V and corresponding lattice spacing information

Figure S12 shows the TEM characterization and lattice fringe test results of CZT after discharging to 0.01 V. It can be observed that there are many lattice fringes characterized in the electrode material, and the lattice spacing is approximately 0.225 nm after local magnification and measurement. Corresponding to the (311) crystal plane of K_2Te , the CZT composite material exhibits conversion-type negative electrode characteristics. Combining with the previous studies on K^+ storage of ZnTe and $CoTe_2$ separately, it is concluded that the K^+ storage reaction of CZT is:

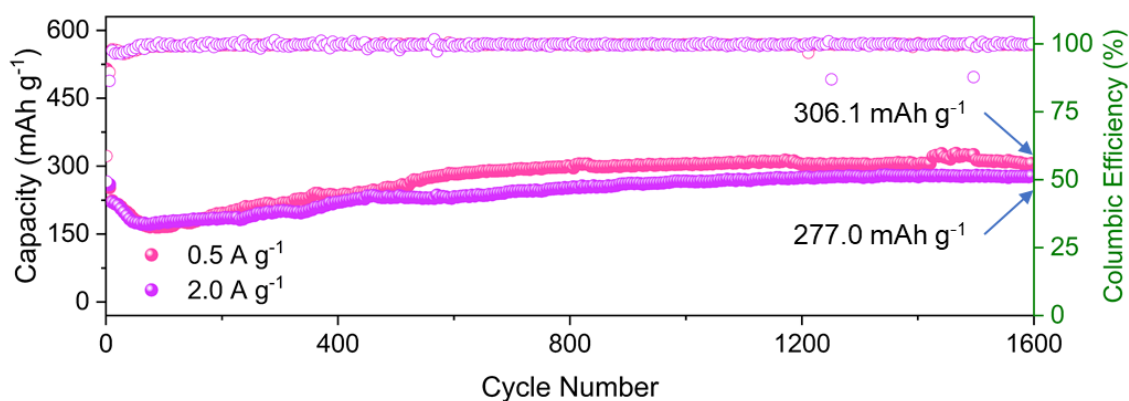
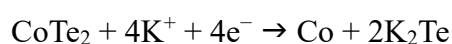
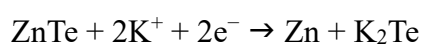


Fig. S13 Cycle performance of CZT at a current density of 0.5 and 2.0 $A g^{-1}$

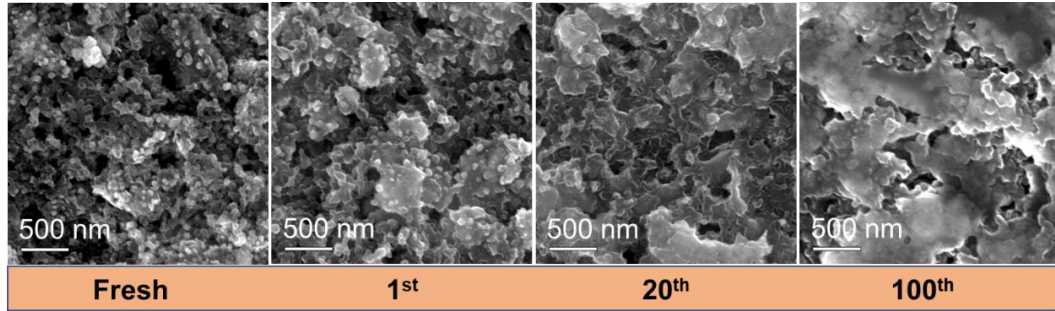


Fig. S14 Postmortem SEM images of CZT tested at 0.5 A g^{-1} after various cycles

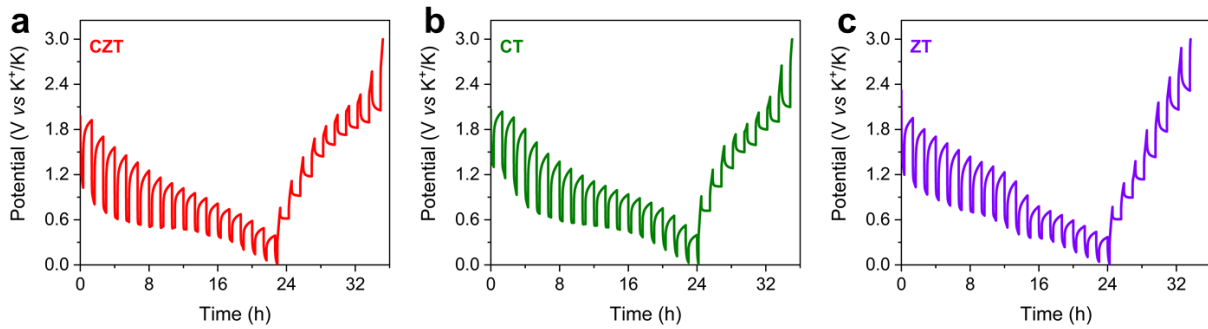


Fig. S15 The voltage-time curves of CZT, CT, and ZT in the GITT test

The K^+ diffusion coefficients were calculated based on the diffusion formula:

$$D_{\text{K}^+} = \frac{4}{\pi\tau} \left(\frac{m_B V_M}{M_B S} \right)^2 \left(\frac{\Delta E_s}{\Delta E_t} \right)^2$$

Where τ represents the relaxation time, m_B and S refer to the mass and area of the electrode. V_M and M_B denote the molar volume and molar mass of the electrode. ΔE_s represents the steady-state voltage change, and ΔE_t represents the transient voltage change.

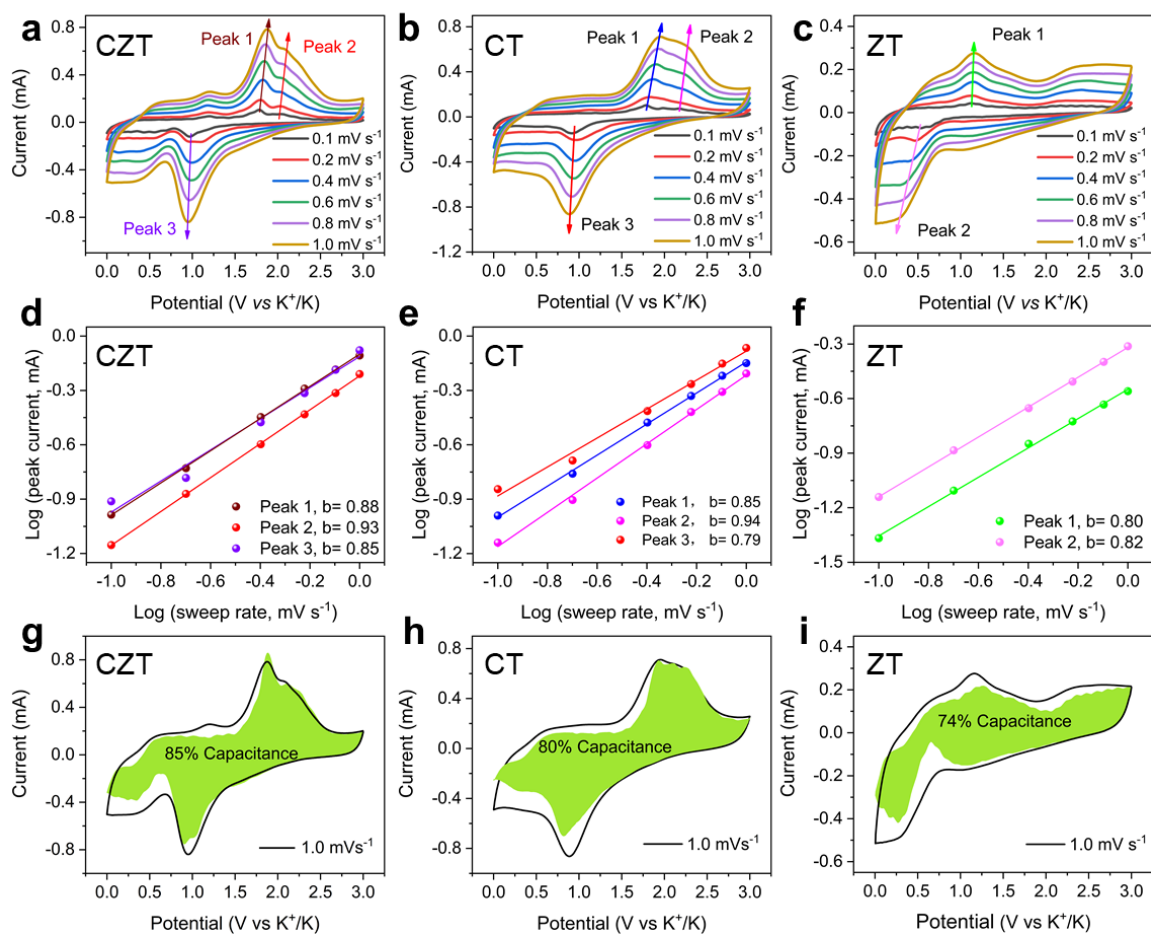


Fig. S16 (a-c) CV curves of (a) CZT, (b) CT and (c) ZT at various sweeping rates; (d-f) Relationship between peak current and sweeping rate of (d) CZT, (e) CT and (f) ZT; (g,h,i) Capacitive contribution of (g) CZT, (h) CT and (i) ZT at a sweeping rate of 1.0 mV s⁻¹

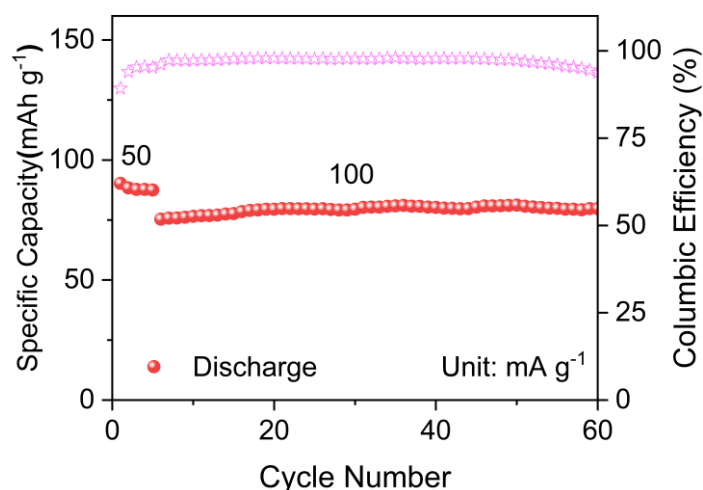


Fig. S17 Cycling performance of KPB half cells at a current density of 100 mA g⁻¹ (note that the cell was cycled at 50 mA g⁻¹ for the first 5 cycles). Half cells were assembled using K metal as the counter electrode

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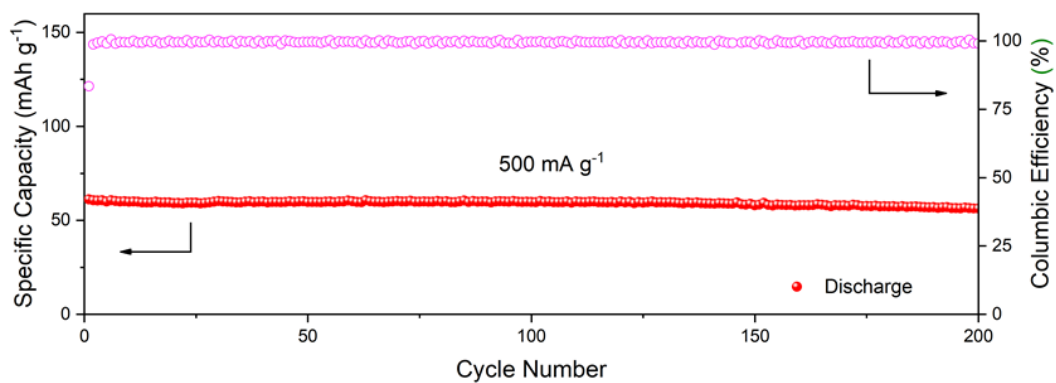


Fig. S18 Cycle performances of KPBCZT full cells at a current density of 500 mA g⁻¹

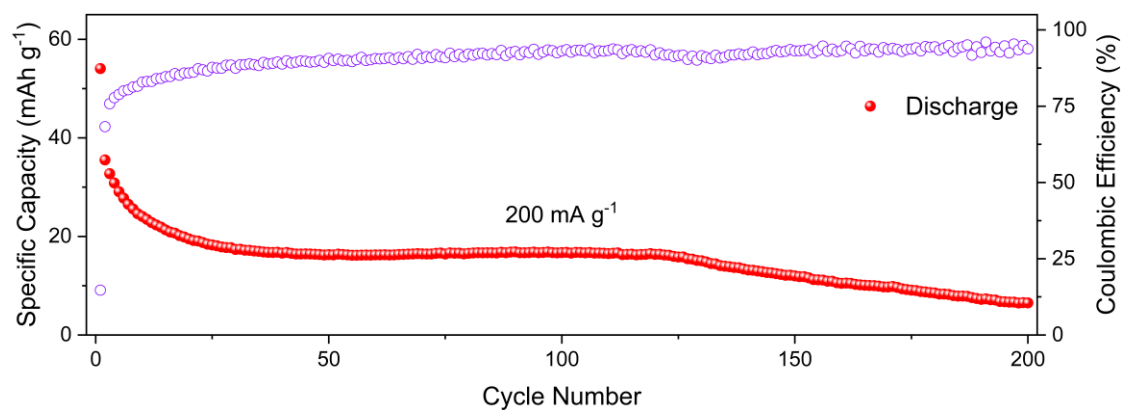


Fig. S19 Cycling performance of KPBCZT full cells at a current density of 200 mA g⁻¹ without pre-potassiation of anodes